## Most Frequently Occurring Classifications of Patents Returned From A Search of 10/720,249 on August 26, 2005

## **Combined Classifications**

19	257/E27.099
11	257/903
8	
8	257/E21.576
8	257/E21.582
8	257/E21.585
8	257/E21.633
8	257/E21.661
8	257/E23.039
8	257/E23.118
8	257/E23.15
	257/E23.154
	257/E23.179
8	
	257/393
6	
	257/E27.112
5	257/69
5	257/904
5	257/E21.54
4	257/206
4	257/336
4	257/385
4	257/401
4	257/E21.648
4	438/238
3	257/365
3	257/368
3	257/390
3	257/E21.008
3	257/E21.703
3 3 2	365/154
3	365/156
3	438/649
2	257/208
2	438/688

2	257/296 257/300 257/301 257/305 257/316 257/338 257/344 257/347 257/350 257/366 257/378 257/379 257/503 257/59 257/68 257/71 257/F23 153 257/F23 163 257/E23 163 257/E27 081 257/E27 084 257/E27 101 257/E27 101 257/E29 136 257/E29 275 257/E29 299 327/566 365/185 13 365/208 438/210 438/231 438/275 438/302
2	257/300
2	257/301
2	257/305
2	257/316
2	257/338
2	257/344
2	257/347
2	257/350
2	257/366
2	257/378
2	257/379
2	257/380
2	257/503
2	257/59
2	257/00
2	257/763
2	257/770
2	257/770 257/E21.415 257/E23.153
2	257/E21.413
2	257/E23.163
2	257/E27.081
2	257/E27.084
2	257/E27.101
2	257/E27.101 257/E29.136
2	257/E29.275
2	257/E29.299
2	327/566
2	365/185.13
2	365/208
2	438/210
2	438/231
2	438/275
2	438/302

## 10720249\_CLSTITLES1.txt Titles of Most Frequently Occurring Classifications of Patents Returned From A Search of 10/720,249 on August 26, 2005

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003 (0 OR, 11 XR)
Class 257: ACTIVE SOLID-STATE DEVICES
Could not find subclass title.
 11 257/903
                        (2 OR, 4 XR)
            Class
                       257 : ACTIVE SOLID-STATE DEVICES
            257/264
                              ... Enhancement mode or with high resistivity
                              channel (e.g., doping of 10 15 cm -3 or less)
.Having insulated electrode (e.g., MOSFET, MOS
            257/288
                                     diode)
            257/368
                              .. Insulated gate field effect transistor in
                                   integrated circuit
            257/393
                              ...Insulated gate field effect transistor
                                  adapted to function as load element for switching
insulated
                                  gate field effect transistor
                       (1 OR, 4 XR)
257 : ACTIVE SOLID-STATE DEVICES
    257/69
            Class
            257/49
                              NON-SINGLE CRYSTAL, OR RECRYSTALLIZED,
                                      SEMICONDUCTOR MATERIAL FORMS PART OF ACTIVE JUNCTION
                                      (INCLUDING FIELD-INDUCED ACTIVE JUNCTION)
                              Field effect device in non-single crystal, or recrystallized, Semiconductor material ...In combination with device formed in single
            257/66
            257/67
                                   crystal semiconductor material (e.g., stacked FETs)
            257/69
                              ...Field effect transistor in single crystal
                                  material, complementary to that in non-single crystal, or recrystallized, material (e.g., CMOS)
  5 257/904
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## PLUS Search Results for S/N 10/720,249, Searched August 26, 2005 (Top 50)

The Patent Linguistics Utility System (PLUS) is a USPTO automated search system for U.S. Patents from 1971 to the present. PLUS is a query-by-example search system which produces a list of patents that are most closely related linguistically to the application searched. This search was prepared by the staff of the Scientific and Technical Information Center, SIRA

5543652	6927414	5731219	6586807	6169324
5388067	5523598	5754467	6897499	6172861
6063686	5854497	5767554	5202275	5017507
5371401	5594270	5834851	5319221	5410173
6043536	5798551	5946565	5331191	5467048
6638799	5239196	6211004	5557147	5514895
5696386	5572480	6211004	5739589	5683921
6617651	5652457	6307217	5780882	6020228
6650565	5656836	6466054	5811316	6064093
6897531	5700704	6512245	6127255	6165825